TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

# SSM6N7002AFU

High Speed Switching Applications

Analog Switch Applications

- Small package
- Low ON resistance

:  $R_{on} = 3.3 \Omega \text{ (max)} (@V_{GS} = 4.5 \text{ V})$ 

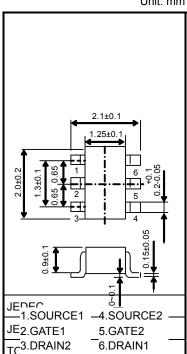
:  $R_{on} = 3.2 \Omega (max) (@V_{GS} = 5 V)$ 

:  $R_{on} = 3.0 \ \Omega \text{ (max)} (@V_{GS} = 10 \text{ V})$ 

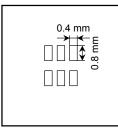
#### Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V <sub>DS</sub>	60	V	
Gate-Source voltage		V <sub>GSS</sub>	$\pm20$	V	
Drain current	DC	I <sub>D</sub>	200	mA	
	Pulse	I <sub>DP</sub>	800		
Drain power dissipation (Ta = $25^{\circ}$ C)		P <sub>D</sub> (Note)	300	mW	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	

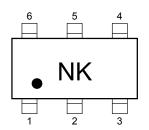
Note: Total rating, mounted on FR4 board (25.4 mm  $\times$  25.4 mm  $\times$  1.6 t, Cu Pad: 0.32mm<sup>2</sup>  $\times$  6)



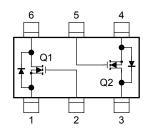
Weight: 0.012 g (typ.)



## Marking



# Equivalent Circuit (top view)



## **Handling Precaution**

When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Downloaded from Elcodis.com electronic components distributor

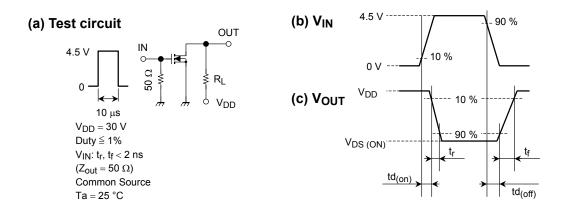
Unit: mm

Electrical Characteristics (Ta = 25°C)

(Q1, Q2 Common)

Characteristics		Symbol	Test Condition	Min	Тур	Max	Unit
Gate leakage current		I <sub>GSS</sub>	$V_{GS}=\pm20$ V, $V_{DS}=0$ V	_		±0.1	μA
Drain-source breakdown voltage		V (BR) DSS	$I_D = 0.1 \text{ mA}, V_{GS} = 0 \text{ V}$	60	_	_	V
Drain cutoff current		I <sub>DSS</sub>	$V_{DS} = 60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$		_	1	μA
Gate threshold vo	Itage	V <sub>th</sub>	$V_{DS} = 10 \text{ V}, I_D = 0.25 \text{ mA}$	1.0	_	2.5	V
Forward transfer a	admittance	Y <sub>fs</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 200 \text{ mA}$	205	_	_	mS
Drain-source ON-resistance		R <sub>DS (ON)</sub>	$I_D = 500 \text{ mA}, V_{GS} = 10 \text{ V}$	_	1.5	3.0	Ω
			$I_D = 100 \text{ mA}, V_{GS} = 5 \text{ V}$		1.7	3.2	
			$I_D = 100 \text{ mA}, V_{GS} = 4.5 \text{ V}$		1.8	3.3	
Input capacitance		C <sub>iss</sub>			16	_	pF
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = 25 \text{ V}, V_{GS} = 0, \text{ f} = 1 \text{ MHz}$		2.3	_	
Output capacitance		C <sub>oss</sub>	]		6.1		
Switching time	Turn-on delay time	td <sub>(on)</sub>	$V_{DD} = 30 V$ , $I_D = 200 mA$ ,		3	10	ns
	Turn-off delay time	td <sub>(off)</sub>	$V_{GS} = 0$ to 4.5 V		7	20	

#### **Switching Time Test Circuit**

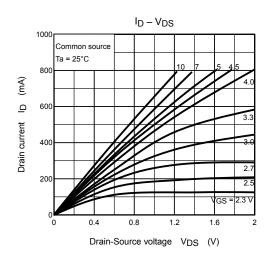


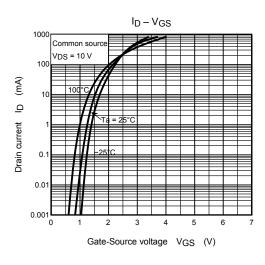
#### Precaution

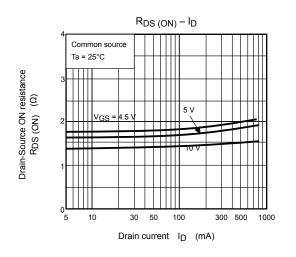
 $V_{th}$  can be expressed as the voltage between gate and source when the low operating current value is I<sub>D</sub>= 0.25 mA for this product. For normal switching operation, V<sub>GS (on)</sub> requires a higher voltage than V<sub>th</sub>, and V<sub>GS (off)</sub> requires a lower voltage than V<sub>th</sub>.

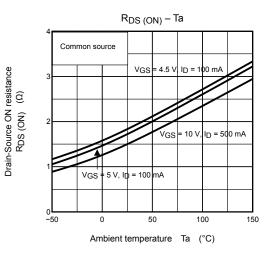
(The relationship can be established as follows:  $V_{GS (off)} < V_{th} < V_{GS (on)}$ .) Take this into consideration when using the device.

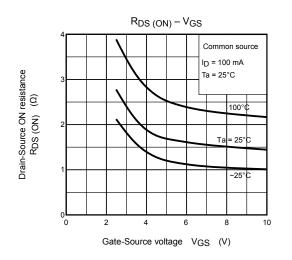
# TOSHIBA

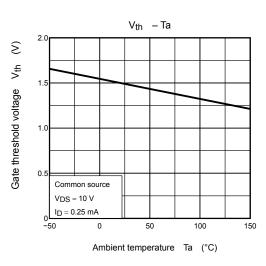


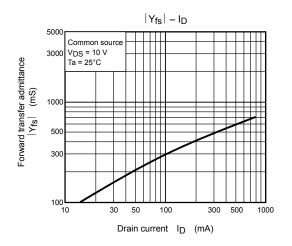


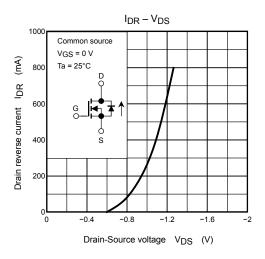


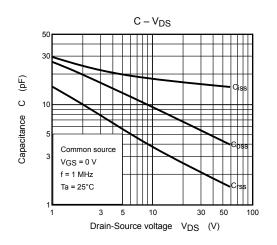


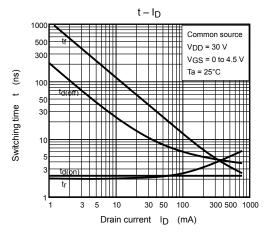


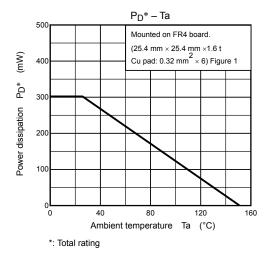












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